



# High Speed CMOS Logic – 74HC14

## Hex Schmitt-Trigger Inverter Logic IC in bare die form

Rev 1.0  
24/11/17

### Description

The 74HC14 Hex Schmitt-Trigger Inverter is fabricated using a 2.5µm 5V CMOS process with the same high speed performance of LSTTL combined with CMOS low power consumption. The device performs the Boolean function  $Y = \bar{A}$  in positive logic. Device inputs are compatible with Standard CMOS outputs; with pull-up resistors, they are compatible with LSTTL outputs. Schmitt-Trigger inputs transform slow input rise and fall times into sharply defined jitter-free output signals. Due to the hysteresis voltage of the Schmitt trigger, the 74HC14 is useful in noisy environments.

### Features:

- Output Drive Capability: 10 LSTTL Loads
- Low Input Current: 1µA
- Outputs directly interface CMOS, NMOS and TTL
- Operating Voltage Range: 2V to 6V
- CMOS High Noise Immunity
- Function compatible with 74LS14.

### Ordering Information

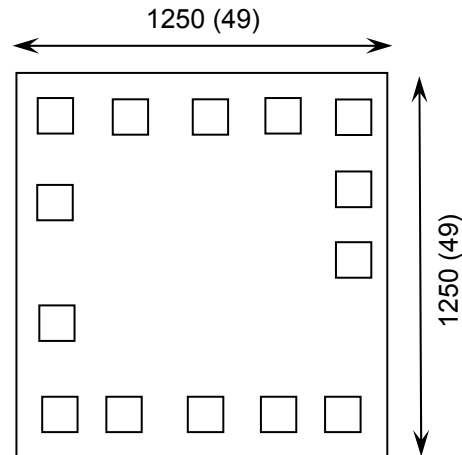
The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection

For High Reliability versions of this product please see

[54HC14](#)

### Die Dimensions in µm (mils)



### Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <=> 350µm(14 Mils) – On request
- Assembled into Ceramic Package – On request

### Mechanical Specification

|                        |                            |            |
|------------------------|----------------------------|------------|
| Die Size (Unsawn)      | 1250 x 1250<br>49 x 49     | µm<br>mils |
| Minimum Bond Pad Size  | 100 x 100<br>3.94 x 3.94   | µm<br>mils |
| Die Thickness          | 350 (±20)<br>13.78 (±0.79) | µm<br>mils |
| Top Metal Composition  | Al 1%Si 1.1µm              |            |
| Back Metal Composition | N/A – Bare Si              |            |

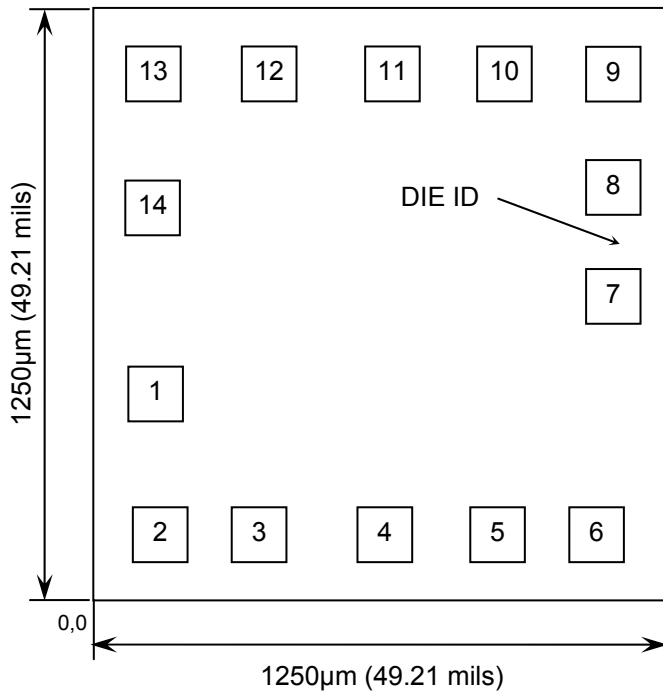




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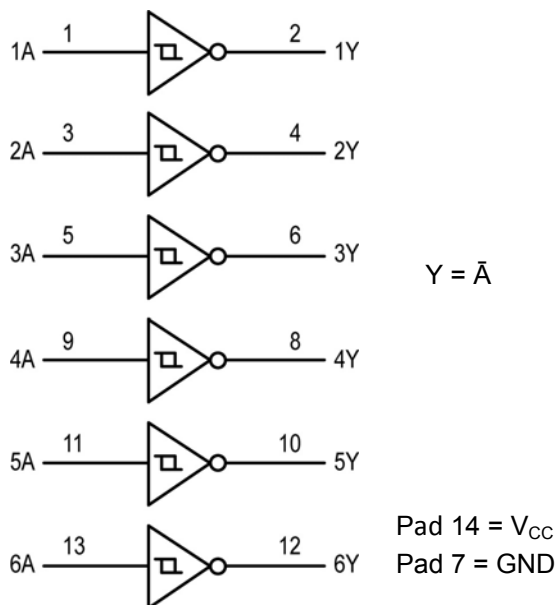
## Pad Layout and Functions



| PAD | FUNCTION        | COORDINATES (mm) |       |
|-----|-----------------|------------------|-------|
|     |                 | X                | Y     |
| 1   | 1A              | 0.14             | 0.345 |
| 2   | 1Y              | 0.14             | 0.141 |
| 3   | 2A              | 0.319            | 0.141 |
| 4   | 2Y              | 0.577            | 0.141 |
| 5   | 3A              | 0.817            | 0.141 |
| 6   | 3Y              | 1.019            | 0.141 |
| 7   | GND             | 1.036            | 0.47  |
| 8   | 4Y              | 1.036            | 0.749 |
| 9   | 4A              | 1.006            | 1.007 |
| 10  | 5Y              | 0.8              | 1.007 |
| 11  | 5A              | 0.584            | 1.007 |
| 12  | 6Y              | 0.334            | 1.007 |
| 13  | 6A              | 0.141            | 0.969 |
| 14  | V <sub>CC</sub> | 0.14             | 0.663 |

CONNECT CHIP BACK TO V<sub>CC</sub> OR FLOAT

## Logic Diagram



## Function Table

| INPUTS<br>A | OUTPUT<br>Y |
|-------------|-------------|
| L           | H           |
| H           | L           |

H = High level (steady state)  
L = Low level (steady state)





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## Absolute Maximum Ratings<sup>1</sup>

| PARAMETER                                   | SYMBOL    | VALUE                  | UNIT |
|---|-----------|------------------------|------|
| DC Supply Voltage (Referenced to GND)       | $V_{CC}$  | -0.5 to +7.0           | V    |
| DC Input Voltage (Referenced to GND)        | $V_{IN}$  | -0.5 to $V_{CC} + 0.5$ | V    |
| DC Output Voltage (Referenced to GND)       | $V_{OUT}$ | -0.5 to $V_{CC} + 0.5$ | V    |
| DC Input Current                            | $I_{IN}$  | ±20                    | mA   |
| DC Output Current, per pad                  | $I_{OUT}$ | ±25                    | mA   |
| DC Supply Current, $V_{CC}$ or GND, per pad | $I_{CC}$  | ±50                    | mA   |
| Power Dissipation in Still Air <sup>2</sup> | $P_D$     | 750                    | mW   |
| Storage Temperature Range                   | $T_{STG}$ | -65 to 150             | °C   |

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

## Recommended Operating Conditions<sup>3</sup> (Voltages Referenced to GND)

| PARAMETER                   | SYMBOL            | MIN             | MAX      | UNITS     |    |
|-----------------------------|-------------------|-----------------|----------|-----------|----|
| Supply Voltage              | $V_{CC}$          | 2               | 6        | V         |    |
| DC Input or Output Voltage  | $V_{IN}, V_{OUT}$ | 0               | $V_{CC}$ | V         |    |
| Operating Temperature Range | $T_J$             | 0               | +85      | °C        |    |
| Input Rise or Fall Times    | $t_r, t_f$        | $V_{CC} = 2.0V$ | -        | No limit* | ns |
|                             |                   | $V_{CC} = 4.5V$ |          |           |    |
|                             |                   | $V_{CC} = 6.0V$ |          |           |    |

\* When  $V_{IN} = 50\% V_{CC}$ ,  $I_{CC} > 1mA$ .

3. This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{IN}$  and  $V_{OUT}$  should be constrained to the range  $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$ . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

## DC Electrical Characteristics (Voltages referenced to GND)

| PARAMETER                                      | SYMBOL      | $V_{CC}$ | CONDITIONS  | LIMITS |      |                         | UNITS |
|--|-------------|----------|---|--------|------|-------------------------|-------|
|  |             |          |   | 25°C   | 85°C | FULL RANGE <sup>4</sup> |       |
| Maximum Positive-Going Input Threshold Voltage | $V_{T+MAX}$ | 2.0V     | $V_{OUT} = 0.1V$<br>$ I_{OUT}  \leq 20\mu A$          | 1.50   | 1.50 | 1.50                    | V     |
|  |             | 3.0V     |   | 2.15   | 2.15 | 2.15                    |       |
|  |             | 4.5V     |   | 3.15   | 3.15 | 3.15                    |       |
|  |             | 6.0V     |   | 4.20   | 4.20 | 4.20                    |       |
| Minimum Positive-Going Input Threshold Voltage | $V_{T+MIN}$ | 2.0V     | $V_{OUT} = 0.1V$<br>$ I_{OUT}  \leq 20\mu A$          | 1.0    | 0.95 | 0.95                    | V     |
|  |             | 3.0V     |   | 1.5    | 1.45 | 1.45                    |       |
|  |             | 4.5V     |   | 2.3    | 2.25 | 2.25                    |       |
|  |             | 6.0V     |   | 3.0    | 2.95 | 2.95                    |       |
| Maximum Negative-Going Input Threshold Voltage | $V_{T-MAX}$ | 2.0V     | $V_{OUT} = V_{CC} - 0.1V$<br>$ I_{OUT}  \leq 20\mu A$ | 0.9    | 0.95 | 0.95                    | V     |
|  |             | 3.0V     |   | 1.4    | 1.45 | 1.45                    |       |
|  |             | 4.5V     |   | 2.0    | 2.05 | 2.05                    |       |
|  |             | 6.0V     |   | 2.6    | 2.65 | 2.65                    |       |





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## DC Electrical Characteristics Continued (Voltages referenced to GND)

| PARAMETER                                      | SYMBOL             | V <sub>CC</sub> | CONDITIONS  | LIMITS |      |                         | UNITS |
|--|--------------------|-----------------|---|--------|------|-------------------------|-------|
|  |                    |                 |   | 25°C   | 85°C | FULL RANGE <sup>4</sup> |       |
| Minimum Negative-Going Input Threshold Voltage | V <sub>T-MIN</sub> | 2.0V            | V <sub>OUT</sub> = V <sub>CC</sub> - 0.1V<br> I <sub>OUT</sub>   ≤ 20μA         | 0.3    | 0.3  | 0.3                     | V     |
|  |                    | 3.0V            |   | 0.5    | 0.5  | 0.5                     |       |
|  |                    | 4.5V            |   | 0.9    | 0.9  | 0.9                     |       |
|  |                    | 6.0V            |   | 1.2    | 1.2  | 1.2                     |       |
| Maximum Hysteresis Voltage <sup>4</sup>        | V <sub>H MAX</sub> | 2.0V            | V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1V<br> I <sub>OUT</sub>   ≤ 20μA | 1.20   | 1.20 | 1.20                    | V     |
|  |                    | 3.0V            |   | 1.65   | 1.65 | 1.65                    |       |
|  |                    | 4.5V            |   | 2.25   | 2.25 | 2.25                    |       |
|  |                    | 6.0V            |   | 3.00   | 3.00 | 3.00                    |       |
| Minimum Hysteresis Voltage <sup>3</sup>        | V <sub>H MIN</sub> | 2.0V            | V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1V<br> I <sub>OUT</sub>   ≤ 20μA | 0.20   | 0.20 | 0.20                    | V     |
|  |                    | 3.0V            |   | 0.25   | 0.25 | 0.25                    |       |
|  |                    | 4.5V            |   | 0.40   | 0.40 | 0.40                    |       |
|  |                    | 6.0V            |   | 0.50   | 0.50 | 0.50                    |       |
| Minimum High-Level Output Voltage              | V <sub>OH</sub>    | 2.0V            | V <sub>IN</sub> ≤ V <sub>T-MIN</sub><br> I <sub>OUT</sub>   ≤ 20μA              | 1.9    | 1.9  | 1.9                     | V     |
|  |                    | 4.5V            |   | 4.4    | 4.4  | 4.4                     |       |
|  |                    | 6.0V            |   | 5.9    | 5.9  | 5.9                     |       |
|  |                    | 3.0V            | V <sub>IN</sub> ≤ V <sub>T-MIN</sub><br> I <sub>OUT</sub>   ≤ 2.4mA             | 2.48   | 2.34 | 2.34                    | V     |
|  |                    | 4.5V            |   | 3.98   | 3.84 | 3.84                    | V     |
|  |                    | 6.0V            |   | 5.48   | 5.34 | 5.34                    | V     |
| Maximum Low-Level Output Voltage               | V <sub>OL</sub>    | 2.0V            | V <sub>IN</sub> ≥ V <sub>T+ MAX</sub><br> I <sub>OUT</sub>   ≤ 20μA             | 0.1    | 0.1  | 0.1                     | V     |
|  |                    | 4.5V            |   | 0.1    | 0.1  | 0.1                     |       |
|  |                    | 6.0V            |   | 0.1    | 0.1  | 0.1                     |       |
|  |                    | 3.0             | V <sub>IN</sub> ≥ V <sub>T+ MAX</sub><br> I <sub>OUT</sub>   ≤ 2.4mA            | 0.26   | 0.33 | 0.33                    | V     |
|  |                    | 4.5V            |   | 0.26   | 0.33 | 0.33                    | V     |
|  |                    | 6.0V            |   | 0.26   | 0.33 | 0.33                    | V     |
| Maximum Input Leakage Current                  | I <sub>IN</sub>    | 6.0V            | V <sub>IN</sub> = V <sub>CC</sub> or GND  | ±0.1   | ±1.0 | ±1.0                    | μA    |
| Maximum Quiescent Supply Current               | I <sub>CC</sub>    | 6.0V            | V <sub>IN</sub> = V <sub>CC</sub> or GND,<br>I <sub>OUT</sub> = 0μA             | 1.0    | 10   | 10                      | μA    |

4. 0°C ≤ T<sub>J</sub> ≤ +85°C 5. V<sub>H MIN</sub> > (V<sub>T+ MIN</sub>) - (V<sub>T- MAX</sub>); V<sub>H MAX</sub> = (V<sub>T+ MAX</sub>) + (V<sub>T- MIN</sub>)





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## AC Electrical Characteristics<sup>6</sup>

| PARAMETER  | SYMBOL                              | V <sub>CC</sub> | CONDITIONS  | LIMITS  |      |                         | UNITS |
|--|-------------------------------------|-----------------|---|---------|------|-------------------------|-------|
|  |                                     |                 |   | 25°C    | 85°C | FULL RANGE <sup>4</sup> |       |
| Maximum Propagation Delay, Input A or B to Output Y (Figure 1) | t <sub>PLH</sub> , t <sub>PHL</sub> | 2.0V            | C <sub>L</sub> = 50pF,<br>t <sub>r</sub> = t <sub>f</sub> = 6ns | 75      | 95   | 95                      | ns    |
|  |                                     | 3.0V            |   | 30      | 40   | 40                      |       |
|  |                                     | 4.5V            |   | 15      | 19   | 19                      |       |
|  |                                     | 6.0V            |   | 13      | 16   | 16                      |       |
| Maximum Transition Time, Any Output (Figure 1)                 | t <sub>TLH</sub> , t <sub>THL</sub> | 2.0V            | C <sub>L</sub> = 50pF,<br>t <sub>r</sub> = t <sub>f</sub> = 6ns | 75      | 95   | 95                      | ns    |
|  |                                     | 3.0V            |   | 27      | 32   | 32                      |       |
|  |                                     | 4.5V            |   | 15      | 19   | 19                      |       |
|  |                                     | 6.0V            |   | 13      | 16   | 16                      |       |
| Maximum Input Capacitance                                      | C <sub>IN</sub>                     | -               | -   | 10      | 10   | 10                      | pF    |
| Power Dissipation Capacitance <sup>7</sup>                     | C <sub>PD</sub>                     | -               | T <sub>J</sub> = 25°C, V <sub>CC</sub> = 5.0V                   | TYPICAL |      |                         | pF    |
|  |                                     |                 |   | 22      |      |                         |       |

6. Not production tested in die form, characterized by chip design and tested in package LAT.

7. Used to determine the no-load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

## Switching Waveform

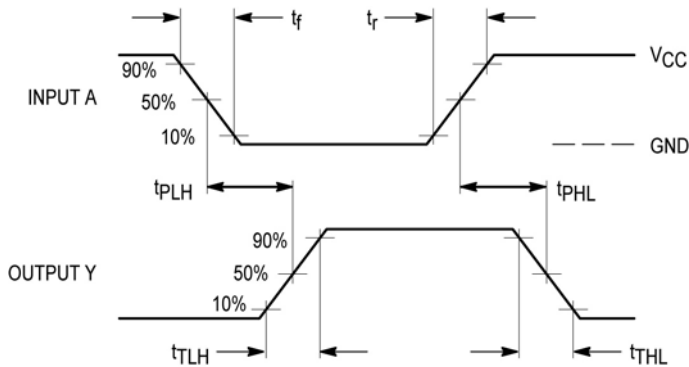
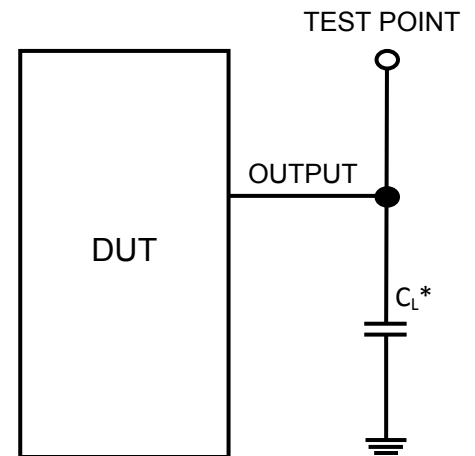


Figure 1 – Propagation Delay, Transition Timing

## Test Circuit



\* Includes all probe and jig capacitance

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